NSN 5961-00-989-9616 Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-989-9616
Inclosure Material:
Metal
Overall Length:
0.394 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Base
Mounting Method:
Threaded stud
Terminal Circle Diameter:
0.185 inches
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
0.437 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 8.0
breakdown voltage, emitter-to-base, collector open
Current Rating Per Characteristic:
10.00 milliamperes source cutoff current
Power Rating Per Characteristic:
30.0 watts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
99971-7618494 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0